October 2007

STEALTHTM II Rectifier

FAIRCHILD

SEMICONDUCTOR

FFP30S60S

Features

- + High Speed Switching, t_{rr} < 40ns @ I_F = 30A
- High Reverse Voltage and High Reliability
- RoHS compliant

Applications

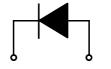
- General Purpose
- Switching Mode Power Supply
- Boost Diode in continuous mode power factor corrections
- Power switching circuits



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Pin Assigments





30A, 600V STEALTH™ II Rectifier

reducing power loss in the switching transistors.

planar construction.

The FFP30S60S is STEALTH[™] II rectifier with soft recovery

charac-teristics. It is silicon nitride passivated ion-implanted epi-

This device is intended for use as freewheeling of boost diode in switching power supplies and other power swithching applica-

tions. Their low stored charge and hyperfast soft recovery minimize ringing and electrical noise in many power switching circuits

1. Cathode 2. Anode

Absolute Maximum Ratings T_C = 25°C unless otherwise noted

Symbol	Parameter	Ratings	Units	
V _{RRM}	Peak Repetitive Reverse Voltage	600	V	
V _{RWM}	Working Peak Reverse Voltage	600	V	
V _R	DC Blocking Voltage	600	V	
I _{F(AV)}	Average Rectified Forward Current $@ T_C = 103^{\circ}C$	30	А	
I _{FSM}	Non-repetitive Peak Surge Current 60Hz Single Half-Sine Wave	300	А	
T _J , T _{STG}	Operating and Storage Temperature Range	-65 to +150	°C	

Thermal Characteristics

Symbol	Parameter	Ratings	Units
$R_{ ext{ heta}JC}$	Maximum Thermal Resistance, Junction to Case	1.1	°C/W

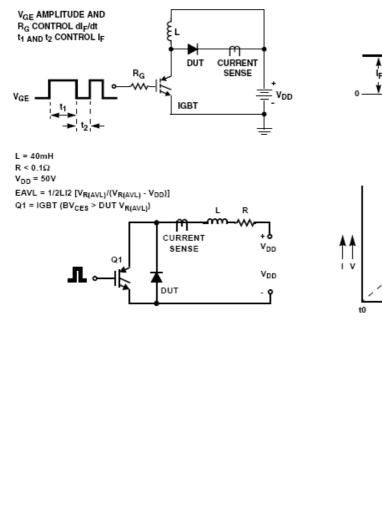
Package Marking and Ordering Information

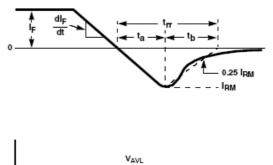
Device Marking	Device	Package	Reel Size	Tape Width	Quantity
F30S60S	FFP30S60STU	TO-220-2L	-	-	50

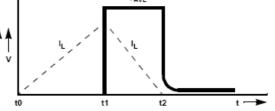
Symbol	Parameter	Min.	Тур.	Max.	Units	
V _{FM} 1	I _F = 30A I _F = 30A	$T_C = 25^{\circ}C$ $T_C = 125^{\circ}C$		2.1 1.6	2.6 -	V
I _{RM} 1	V _R = 600V V _R = 600V	$T_{C} = 25^{\circ}C$ $T_{C} = 125^{\circ}C$		-	100 500	μΑ
t _{rr}	$I_{F} = 1A$, di/dt = 100A/µs, $V_{R} = 30V$	$T_C = 25^{\circ}C$	-	25	35	ns
t _{rr} I _{rr} S factor Q _{rr}	I _F = 30A, di/dt = 200A/µs, V _R = 390V	T _C = 25°C		28 2.4 0.9 34	40 - - -	ns A nC
^t rr I _{rr} S factor Q _{rr}	I _F = 30A, di/dt = 200A/µs, V _R = 390V	T _C = 125°C		75 6.3 0.9 236		ns A nC
W _{AVL}	Avalanche Energy (L = 40mH)		20	-	-	mJ

Notes: 1: Pulse: Test Pulse width = 300μ s, Duty Cycle = 2%

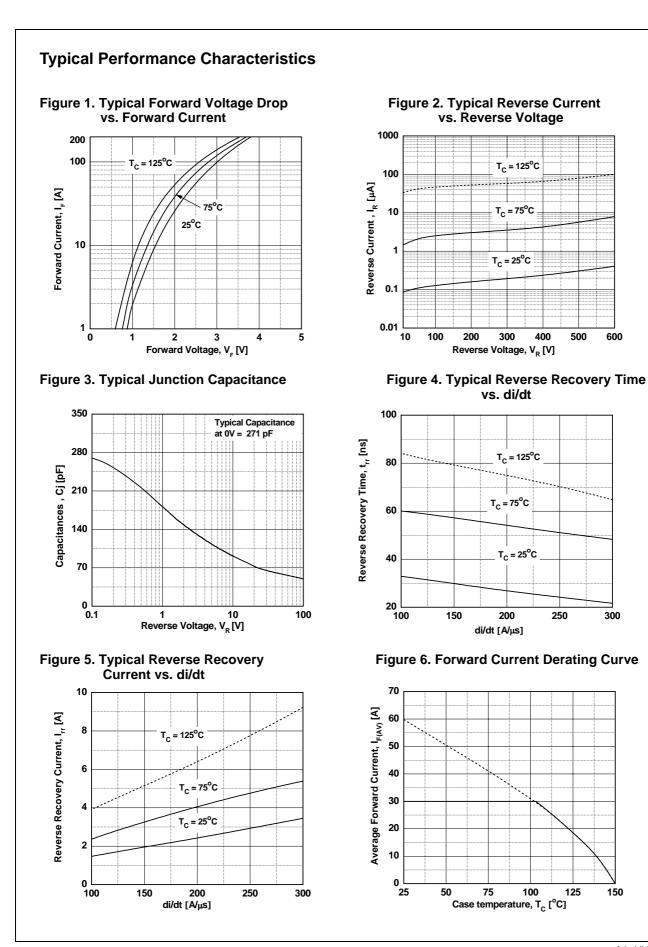
Test Circuit and Waveforms





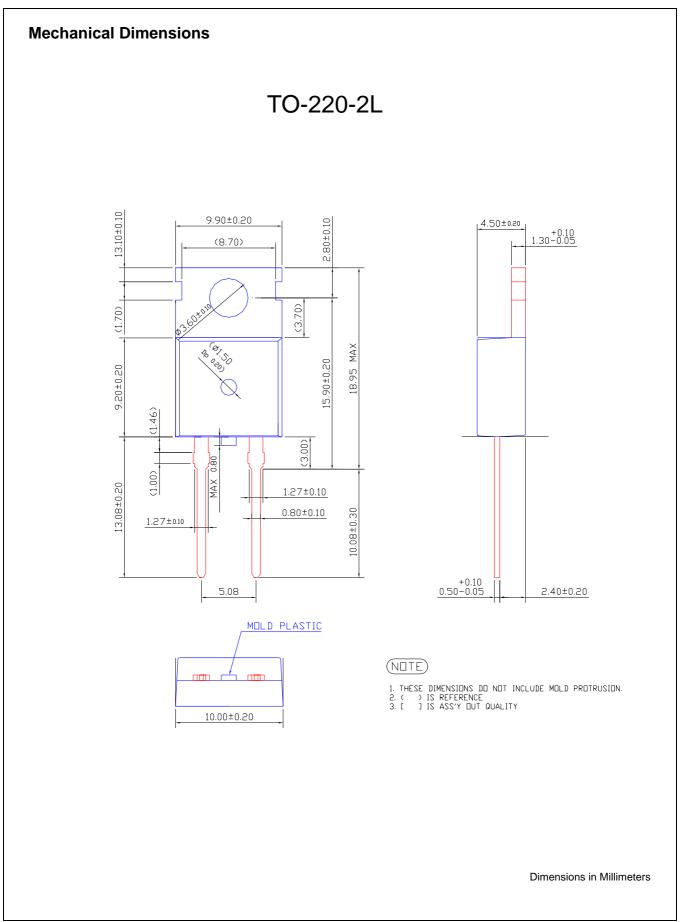


FFP30S60S



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FFP30S60S Rev. A



FFP30S60S



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